SCS210AGHR

Automotive Grade SiC Schottky Barrier Diode

Datasheet

V_R	650V
I _F	10A
Q_{C}	15nC

Outline TO-220AC (1) (2) (3)

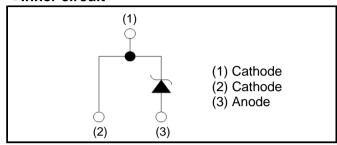
Features

- 1) AEC-Q101 qualified
- 2) Low forward voltage
- 3) Negligible recovery time/current
- 4) Temperature independent switching behavior

Applications

- · On Board Charger
- DC/DC Converter
- · Wireless Charger
- EV Charger

•Inner circuit



Packaging specifications

	<u> </u>	
	Packaging	Tube
	Reel size (mm)	-
Typo	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	С
	Marking	SCS210AG

● Absolute maximum ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (re	petitive peak)	V_{RM}	650	V
Reverse voltage (D	C)	V _R	650	V
Continuous forward	current (T _c = 135°C)	I _F	10	А
Surge non-			38	А
repetitive forward	PW=10ms sinusoidal, T _j =150°C	I_{FSM}	30	А
current	PW=10μs square, T _j =25°C		150	А
Repetitive peak forward current		I _{FRM}	44 *1	А
PW=10ms, T _j =25°C		$\int i^2 dt$	7.2	A ² s
i^2 t value PW=10ms, T _j =150°C		J i⁻dt	4.5	A ² s
Total power dissipation		P_{D}	78 ^{*2}	W
Junction temperature		T _j	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

•Electrical characteristics $(T_j = 25^{\circ}C)$

Parameter	Symbol	Conditions	Values			Linit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =2.0mA	650	-	-	V
	V _F	I _F =10A,T _j =25°C	-	1.35	1.55	V
Forward voltage		I _F =10A,T _j =150°C	-	1.55	-	V
		I _F =10A,T _j =175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V,T _j =25°C	-	2	200	μΑ
		V _R =600V,T _j =150°C	-	30	-	μΑ
		V _R =600V,T _j =175°C	-	70	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	360	-	pF
		V _R =600V,f=1MHz	-	37	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	15	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	ı	15	-	ns

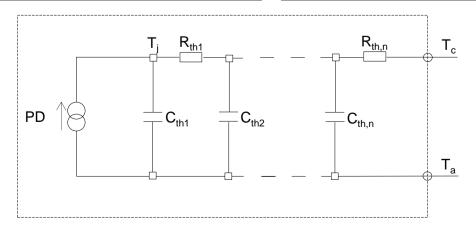
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	UIIIL
Thermal resistance	$R_{\text{th(j-c)}}$	-	ı	1.6	1.9	°C/W

● Typical Transient Thermal Characteristics

Symbol	Value	Unit
R _{th1}	5.71E-01	
R _{th2}	1.02E+00	K/W
R _{th3}	5.32E-03	

Symbol	Value	Unit
C_{th1}	1.65E-03	
C_{th2}	5.88E-03	Ws/K
C_{th3}	3.43E-01	



Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

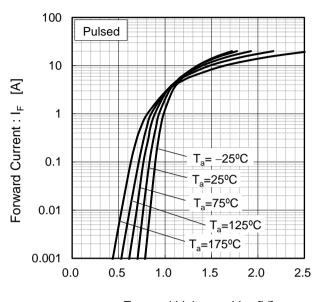
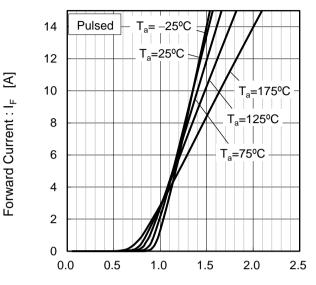


Fig.2 V_F - I_F Characteristics



Forward Voltage: V_F [V]

Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics

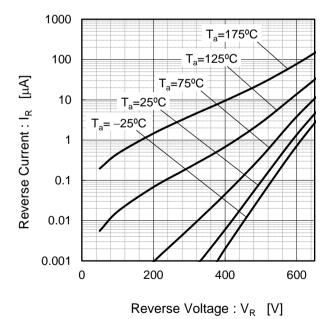
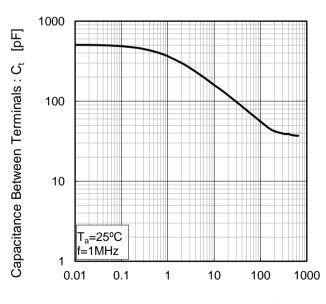


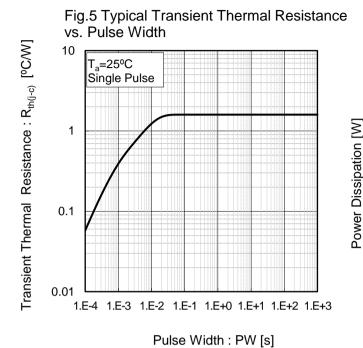
Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

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• Electrical characteristic curves



90 80 70 60 50 40 30 20 10 175 25 50 75 100 125 150

Case Temperature : T_c [°C]

Fig.6 Power Dissipation

Fig.7*3 Maximum peak forward current derating curve I_P - T_c 120 100 Peak Forward Current: Ip [A] 80 Duty=0.1 60 Duty=0.2 40 Duty=0.5 20 Duty=0.8 D.C 0 25 50 75 100 125 150 175

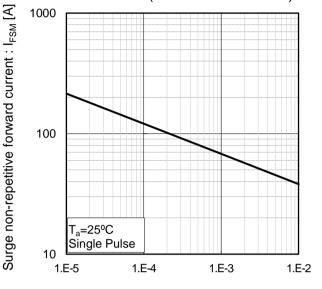
Case Temperature : T_c [°C] *3 Based on max Vf, max R_{th(j-c)} Valid for switching of above 10kHz, excluding D.C. curve.

derating curve I_P - T_c (Not guaranteed) 120 100 Duty=0.1 Peak Forward Current : Ip [A] 80 Duty=0.2 60 Duty=0.5 40 20 Duty=0.8 D.C. 0 25 50 75 100 125 150 175

Fig.8*4 Typical peak forward current

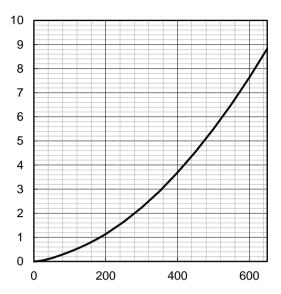
Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

Fig.10 Typical capacitance store energy

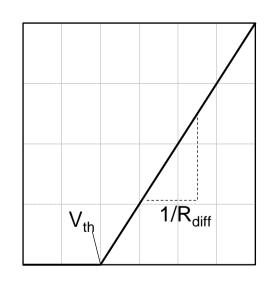


Capacitance stored energy : E_C[പ്വ]

Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th} \left(\ T_{j} \ \right) = a_{0} + a_{1} \, T_{j} \\ &R_{diff} \left(\ T_{j} \ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a_0	9.35E-01	V
a ₁	-1.12E-03	V/°C
b ₀	3.98E-02	Ω
b ₁	1.02E-04	Ω/°C
b ₂	1.08E-06	$\Omega/^{\circ}C^{2}$

 T_i in °C; -55 °C < T_i < °C; I_F < 20 A

Forward Current: IF

29.Jun.2018 - Rev.003

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